

SCHOTTKY BARRIER DIODE

Features

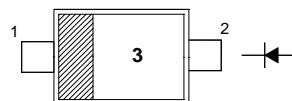
- Low forward voltage

Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Marking Code: "3"
Simplified outline SOD-523 and symbol

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	30	V
Forward Current	I_F	200	mA
Repetitive Peak Forward Current	I_{FRM}	300	mA
Peak Forward Surge Current ($t_p = 10 \text{ ms}$)	I_{FSM}	600	mA
Power Dissipation	P_D	200	mW
Thermal Resistance from Junction Ambient	R_{thJA}	500	K/W
Junction Temperature	T_J	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min	Max.	Unit
Forward Voltage at $I_F = 0.1 \text{ mA}$ at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 30 \text{ mA}$ at $I_F = 100 \text{ mA}$	V_F	- - - - -	0.24 0.32 0.4 0.5 0.8	V
Reverse Breakdown Voltage at $I_R = 10 \mu\text{A}$	$V_{(BR)R}$	30	-	V
Reverse Current at $V_R = 25 \text{ V}$	I_R	-	2	μA
Total Capacitance at $V_R = 1 \text{ V}, f = 1 \text{ MHz}$	C_T	-	15	pF
Reverse Recovery Time at $I_F = 10 \text{ mA}, V_R = 6 \text{ V}, I_R = 10 \text{ mA}, R_L = 100 \Omega$	t_{rr}	-	6	ns

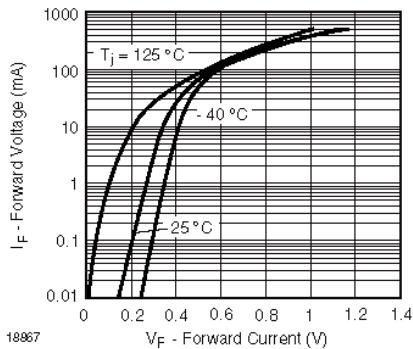


Figure 1. Typical Forward Voltage Forward Current at Various Temperatures

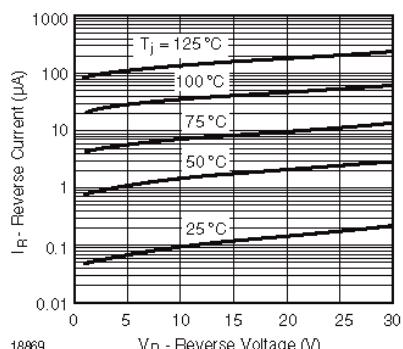


Figure 3. Typical Variation of Reverse Current at Various Temperatures

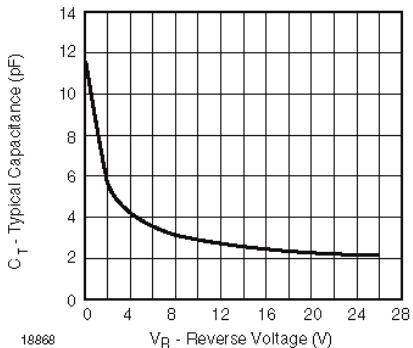
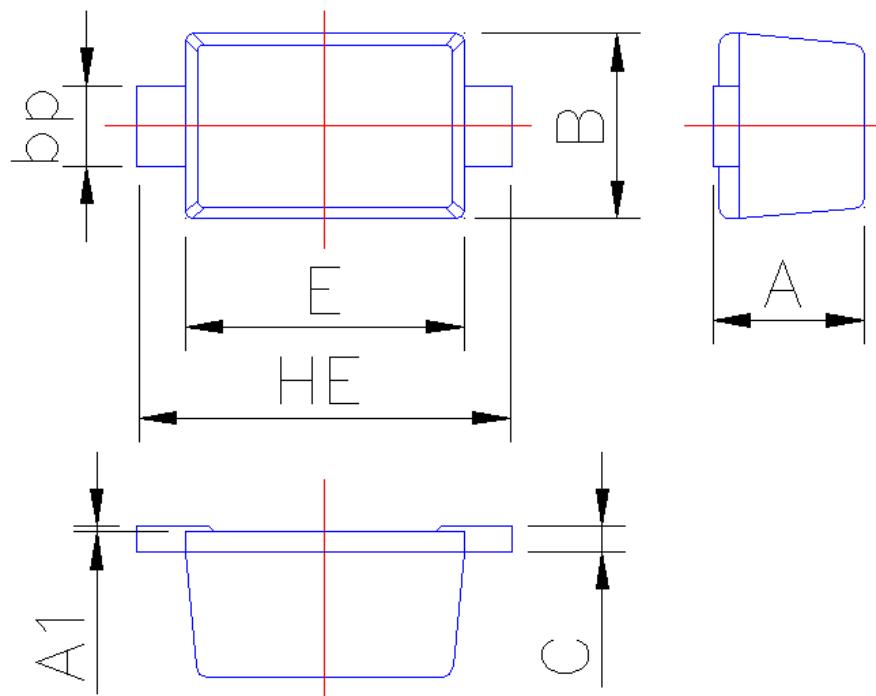


Figure 2. Typical Capacitance ${}^\circ\text{C}$ vs. Reverse Applied Voltage V_R

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-523



Symbol	Dimension in Millimeters	
	Min	Max
A	0.60	0.70
A1	0	0.05
B	0.75	0.85
bp	0.25	0.40
C	0.09	0.15
E	1.15	1.25
HE	1.50	1.70